



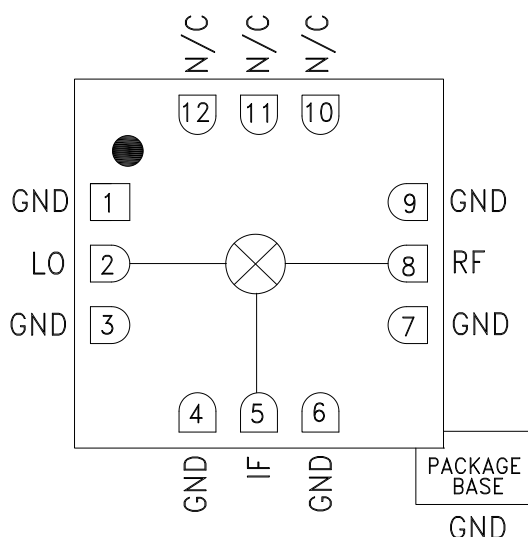
## GaAs MMIC FUNDAMENTAL MIXER, 5.5 - 14.0 GHz

### Typical Applications

The HMC558LC3B is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- Test Equipment & Sensors
- Military End-Use

### Functional Diagram



### Features

- Passive Double Balanced Topology
- High LO/RF Isolation: 45 dB
- Low Conversion Loss: 7 dB
- Wide IF Bandwidth: DC - 6 GHz
- 12 Lead Ceramic 3x3mm SMT Package: 9mm<sup>2</sup>

### General Description

The HMC558LC3B is a general purpose double balanced mixer in a leadless RoHS compliant SMT package that can be used as an upconverter or downconverter between 5.5 and 14 GHz. This mixer is fabricated in a GaAs MESFET process, and requires no external components or matching circuitry. The HMC558LC3B provides excellent LO to RF and LO to IF isolation due to optimized balun structures and operates with LO drive levels as low as +9 dBm. The RoHS compliant HMC558LC3B eliminates the need for wire bonding, and is compatible with high volume surface mount manufacturing techniques.

### Electrical Specifications, $T_A = +25^\circ\text{C}$ , $IF = 100\text{ MHz}$ , $LO = +15\text{ dBm}^*$

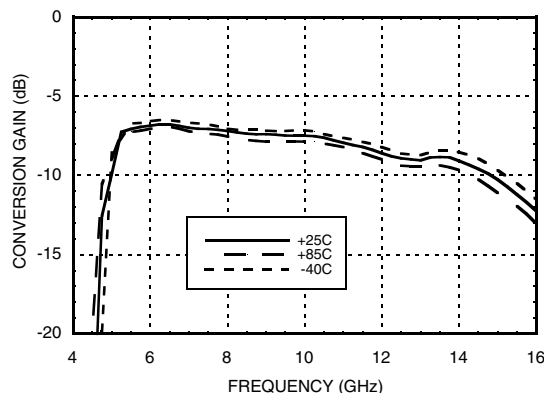
Parameter	Min.	Typ.	Max.	Min.	Typ.	Max.	Units
Frequency Range, RF & LO		5.5 - 10.0		10.0 - 14.0			GHz
Frequency Range, IF		DC - 6		DC - 6			GHz
Conversion Loss		7	9.5		8.5	10	dB
Noise Figure (SSB)		7	9.5		8.5	10	dB
LO to RF Isolation	35	45		30	36		dB
LO to IF Isolation	20	25		20	25		dB
RF to IF Isolation	8	14		10	16		dB
IP3 (Input)		20			24		dBm
IP2 (Input)		54			46		dBm
1 dB Gain Compression (Input)		11			13		dBm

\*Unless otherwise noted, all measurements performed as downconverter,  $IF = 100\text{ MHz}$ .

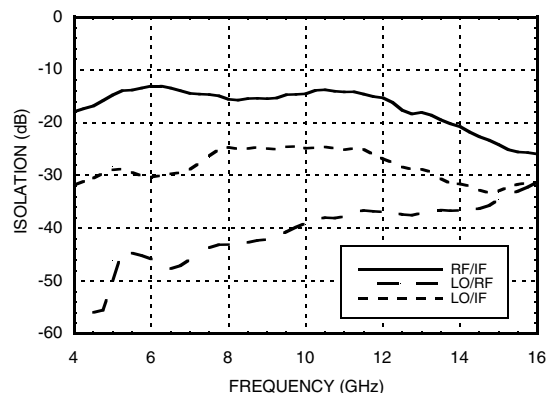


**GaAs MMIC FUNDAMENTAL  
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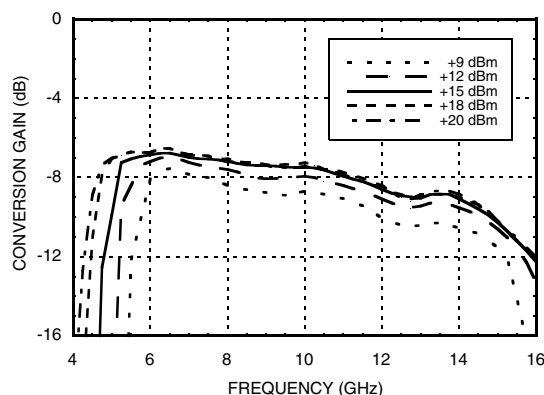
**Conversion Gain vs. Temperature  
@ LO = +15 dBm**



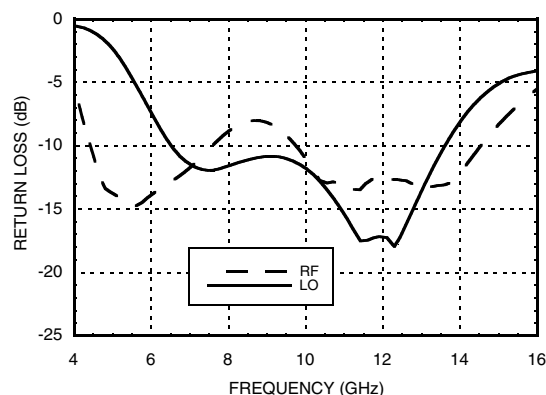
**Isolation @ LO = +15 dBm**



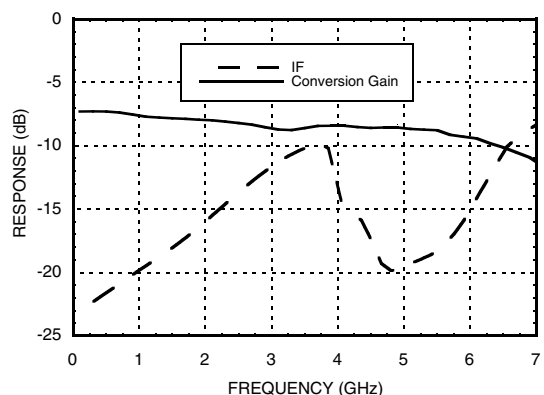
**Conversion Gain vs. LO Drive**



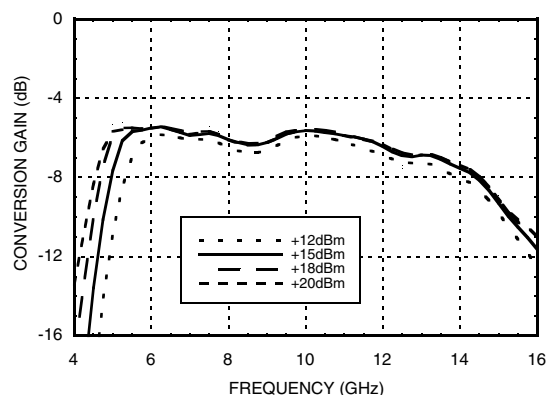
**Return Loss @ LO = +15 dBm**



**IF Bandwidth @ LO = +15 dBm**



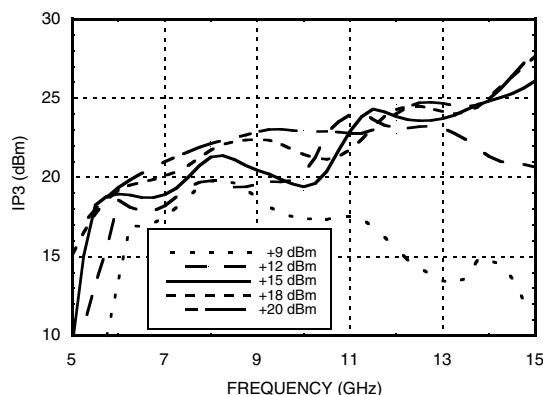
**Upconverter Performance  
Conversion Gain vs. LO Drive**



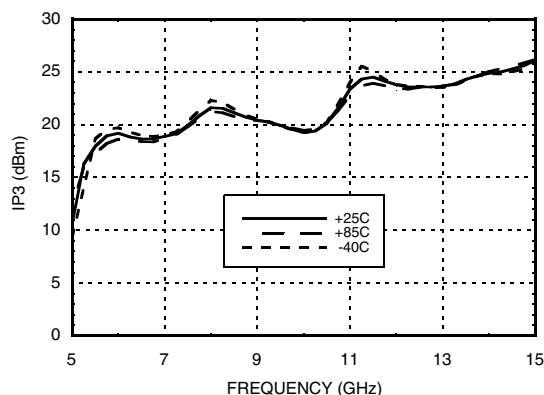


**GaAs MMIC FUNDAMENTAL  
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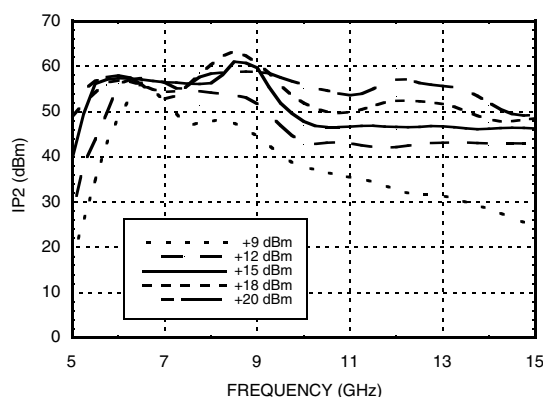
**Input IP3 vs. LO Drive \***



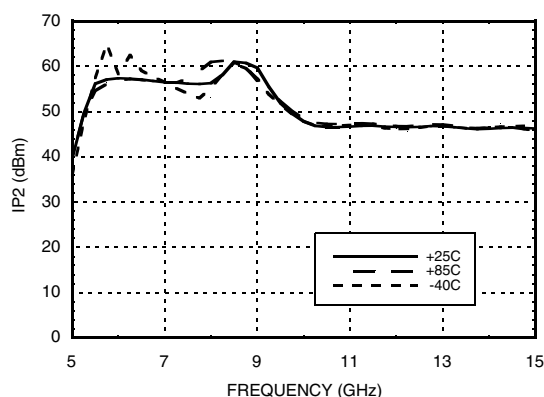
**Input IP3 vs. Temperature  
@ LO = +15 dBm \***



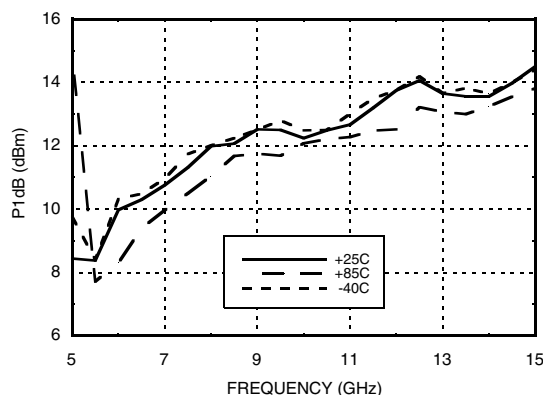
**Input IP2 vs. LO Drive \***



**Input IP2 vs. Temperature  
@ LO = +15 dBm \***



**Input P1dB vs. Temperature  
@ LO = +15 dBm**



**MxN Spurious Outputs**

mRF	nLO				
	0	1	2	3	4
0	xx	-6	22	17	33
1	10	0	25	49	51
2	78	50	82	51	74
3	78	78	75	75	78
4	78	78	78	78	78

RF = 8.1 GHz @ -10 dBm  
LO = 8 GHz @ +15 dBm  
All values in dBc below the IF output power level.

\* Two-tone input power = -10 dBm each tone, 1 MHz spacing.

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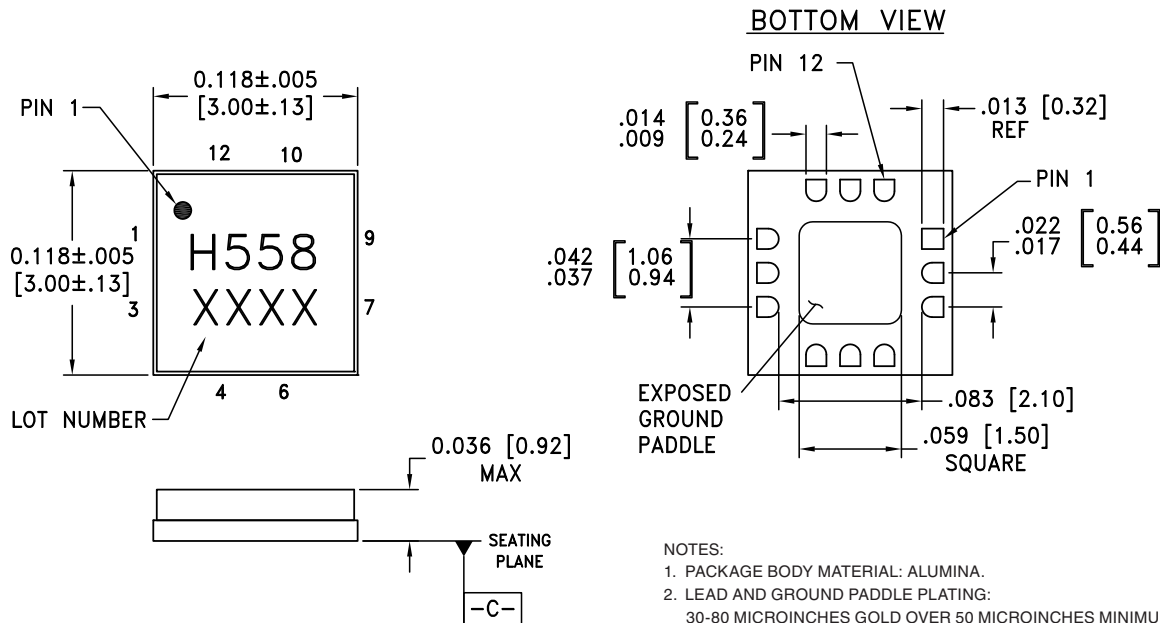
### Absolute Maximum Ratings

RF / IF Input	+25 dBm
LO Drive	+25 dBm
Channel Temperature	150 °C
Continuous Pdiss (T = 85 °C) (derate 3.25 mW/°C above 85 °C)	211 mW
Thermal Resistance (channel to ground paddle)	307 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C



ELECTROSTATIC SENSITIVE DEVICE  
OBSERVE HANDLING PRECAUTIONS

### Outline Drawing




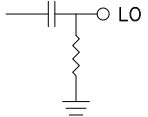
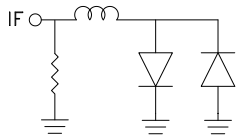
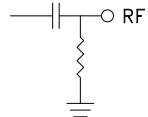
### Package Information

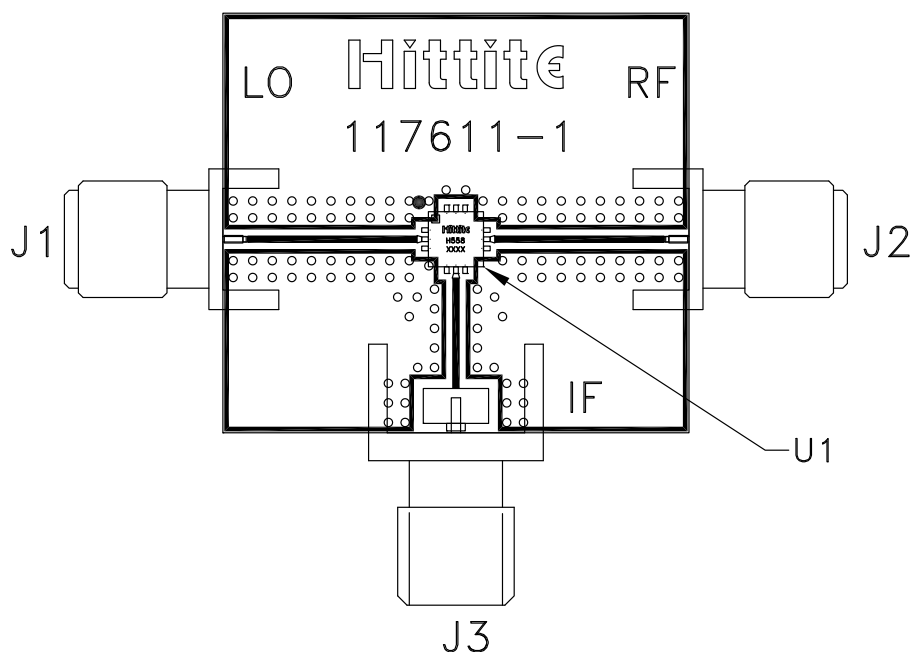
Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking <sup>[2]</sup>
HMC558LC3B	Alumina, White	Gold over Nickel	MSL3 <sup>[1]</sup>	H558 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX


**GaAs MMIC FUNDAMENTAL  
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**Pin Descriptions**

Pin Number	Function	Description	Interface Schematic
1, 3, 4, 6, 7, 9	GND	Package bottom must also be connected to RF/DC ground.	
2	LO	This pin is DC coupled and matched to 50 Ohms.	
5	IF	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source or sink more than 2 mA of current or part non-function and possible part failure will result.	
8	RF	This pin is DC coupled and matched to 50 Ohms.	
10, 11, 12	N/C	No connection required. These pins may be connected to RF/DC ground without affecting performance.	


**GaAs MMIC FUNDAMENTAL  
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**Evaluation PCB**

**List of Materials for Evaluation PCB 109952 <sup>[1]</sup>**

Item	Description
J1 - J2	SRI SMA Connector
J3	Johnson SMA Connector
U1	HMC558LC3B Mixer
PCB [2]	117611 Evaluation PCB

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25 RF

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

# Mouser Electronics

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